Form 1449 (Modified)	Atty Docket No. LAM1P152D1/P0692D	Application No.: Filed Herewith
Information Disclosure	Applicant:	
Statement By Applicant	HO et al.	
	Filing Date	Group
(Use Several Sheets if Necessary)	Herewith	Unassigned

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Examiner						Sub-	Filing
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LV	Α	5,230,772	07/27/93	Kadomura	156	643	07/25/91
	В	5,266,157	11/30/93	Kadomura	156	659.1	10/03/91
	С	5,741,396	04/21/98	Loewenstein	156	643.1	04/29/94
	D	5,814,563	09/29/98	Ding et al.	438	714	06/12/96
*	E	5,877,032	03/02/99	Guinn et al.	438	9	08/27/96
	F	5,970,376	10/19/99	Chen	438	637	12/29/97
	G	6,037,255	03/14/00	Hussein et al.	438	675	05/12/99
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LV	I	6.080,529	06/27/00	Ye et al.	430	318	10/19/98

Foreign Patent or Published Foreign Patent Application

Examiner		Document	Publication	Country or		Sub-	Trans	lation
Initial	No.	No.	Date	Patent Office	Class	class	Yes	No
LV	J	01/04707A1	01/18/01	WIPO	H01L	21/311	Yes	
	K	01/29879A2	04/26/01	WIPO	H01L	N/A	Yes	
	L	01/59825A1	08/16/01	WIPO	HOIL	21/311	Yes	
	M	0851474A2	07/01/98	EPO	H01L	21/321	Yes	
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LV	0	Delsol et al., "Transformer Coupled Plasma Dielectric Etch for 0.25 µm
		Technologies", Microelectronic Engineering 50 (2000), pages 75-80
LV	P	Eto et al., "High Selectivity Photoresist Ashing by the Addition of NH <sub>3</sub> to
		CF <sub>4</sub> /O <sub>2</sub> or CHF <sub>3</sub> /O <sub>2</sub> ", SID 1999 Digest, pages 844-847
	Q	Hasegawa et al., "Copper Dual Damascene Interconnects with Low-K (Keff <
l by		3.0) Dielectrics Using FLARE <sup>TM</sup> and an Organo-Silicate Hard Mask", 1999
		IEEE, pages 26.4.1. – 26.4.4.
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Examiner: Initial citation considered. Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.

Form 1449 (Modified)	Atty Docket No.	Application No.:
	LAM1P152D1/P0692D	Filed Herewith
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20	AA	6,105,588	08/22/00	Li et al.	134	1.1	05/27/98
	BB	6,124,213	09/26/00	Usami et al.	438	710	11/17/98
	CC	6,153,511	11/28/00	Watatani	438	623	06/25/99
	DD	6,174,796B1	01/16/01	Takagi et al.	438	622	12/30/98
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	GG	6,352,918B1	03/05/02	Huang et al.	438	623	11/24/98
	HH	6,352,937B1	03/05/02	Kadomura et al.	438	725	04/27/98
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Initial	No.	No.	Date	Patent Office	Class	class	Yes	No
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	LL							
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LV	00	Lin et al., "Microwave Imaging of Cerebral Edema", Proceedings of the IEEE, Vol. 70, No. 5, May 1982, pages 523-524
LV	PP	Plummer et al., "Silicon VLSI Technology – Fundamentals, Practice and Modeling", Department of Electrical Engineering, Stanford University (2000), page 639
ιV	QQ	International Search Report, dated November 20, 2002
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Examiner: Initial citation considered. Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.

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	ННН						
	III						

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LV	PPP	nternational Search Report, dated July 22, 2003		
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Examiner	LAN	VINH Date Considered, 7/1.1/07		

Examiner: Initial citation considered. Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.